



SPECIFICATION

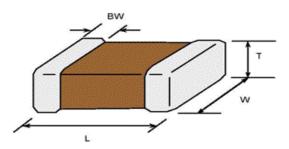
- · Supplier : Samsung electro-mechanics
- Product : Multi-layer Ceramic Capacitor
- Samsung P/N :
 Description :
- CL05A475MQ3LUNC CAP, 4.7uF, 6.3V, ±20%, X5R, 0402

(Reference sheet)

A. Samsung Part Number

			<u>CL</u> ①	<u>05</u> ②	<u>▲</u> ③	<u>475</u> ④	<u>M</u> 5	<mark>Q</mark> ©	<u>3</u> ⑦	<u>L</u> 8	<u>U</u> 9	<u>N</u> 10	<u>С</u> Ш			
1	Series	Samsung	Multi-	layer	Cerar	nic Ca	pacito	or								٦
2	Size	0402 (inch c	ode)		L :	1.00	± 0.20	mm			W :	0.50 ± 0.20	mm		
							8	Thick	ness	divis	ion		Low profile			
3	Dielectric	X5R						Inner	elect	rode			Ni			
4	Capacitance	4.7 เ	μF					Term	inatio	n			Cu			
5	Capacitance	±20 °	%					Platir	ng				Sn 100%	(Pb l	Free)	
	tolerance						9	Prod	uct				Size control	code		
6	Rated Voltage	6.3 \	V				10	Spec	ial				Reserved for	r future	use	
1	Thickness	0.30 ± 0.0)5 mm				1	Pack	aging	I			Cardboard -	Гуре, 7"	' reel	

B. Structure & Dimension



Samsung P/N	Dimension(mm)								
Samsung F/N	L	W	Т	BW					
CL05A475MQ3LUNC	1.00 ± 0.20	0.50 ± 0.20	0.30 ± 0.05	0.25 ± 0.10					

C. Samsung Reliablility Test and Judgement Condition

	Judgement	Test condition				
Capacitance	Within specified tolerance	1 ^{kHz} ±10% / 0.5±0.1Vrms				
Tan δ (DF)	0.125 max.	*A capacitor prior to measuring the capacitance is heat treated at $150^{\circ}C+0/-10^{\circ}C$ for 1hour and maintained in ambient air for 24±2 hours.				
Insulation	10,000Mohm or 50Mohm×µF	Rated Voltage 60~120 sec.				
Resistance	Whichever is smaller					
Appearance	No abnormal exterior appearance	Microscope (×10)				
Withstanding	No dielectric breakdown or	250% of the rated voltage				
Voltage	mechanical breakdown					
Temperature	X5R					
Characteristics	(From-55 ℃ to 85 ℃, Capacitance change s	hould be within ±15%)				
Adhesive Strength	No peeling shall be occur on the	500g·f, for 10±1 sec.				
of Termination	terminal electrode					
Bending Strength	Capacitance change : within ±12.5%	Bending to the limit (1mm)				
		with 1.0mm/sec.				
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder				
	is to be soldered newly	245±5℃, 3±0.3sec.				
		(preheating : 80~120℃ for 10~30sec.)				
Resistance to	Capacitance change : within ±7.5%	Solder pot : 270±5℃, 10±1sec.				
Soldering Heat	Tan δ, IR : initial spec.					
Vibration Test	Capacitance change : within $\pm 5\%$ Tan δ , IR : initial spec.	Amplitude : 1.5mm From 10Hz to 55Hz (return : 1min.) 2hours × 3 direction (x, y, z)				
Moisture	Capacitance change : within ±12.5%	With rated voltage				
Resistance	Tan δ : 0.25 max	40±2℃, 90~95%RH, 500+12/-0hrs				
	IR : 500Mohm or 3.5Mohm × ^µ F					
	Whichever is smaller	With 100% of the rated voltage				
High Temperature Resistance	Capacitance change : within $\pm 12.5\%$ Tan δ : 0.25 max	······				
NESISIAIILE	IR: 1,000Mohm or 7Mohm × μ F	Max. operating temperature 1.000+48/-0hrs				
	Whichever is smaller	1,000+40/-0115				
Temperature	Capacitance change : within ±7.5%	1 cycle condition				
Cycling	Tan δ , IR : initial spec.	Min. operating temperature $\rightarrow 25^{\circ}$ C				
c , cining		\rightarrow Max. operating temperature \rightarrow 25°C				
		5 cycle test				
l						

 $\,\%$ The reliability test condition can be replaced by the corresponding accelerated test condition.

D. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260±5°C, 30sec.)

Product specifications included in the specifications are effective as of March 1, 2013. Please be advised that they are standard product specifications for reference only. We may change, modify or discontinue the product specifications without notice at any time. So, you need to approve the product specifications before placing an order. Should you have any question regarding the product specifications, please contact our sales personnel or application engineers.